

Silicon NPN Power Transistors

2SC5287

DESCRIPTION

- With TO-3PN package
- High voltage,high speed switching

APPLICATIONS

- For switching regulator and general purpose applications

PINNING

PIN	DESCRIPTION
1	Base
2	Collector;connected to mounting base
3	Emitter

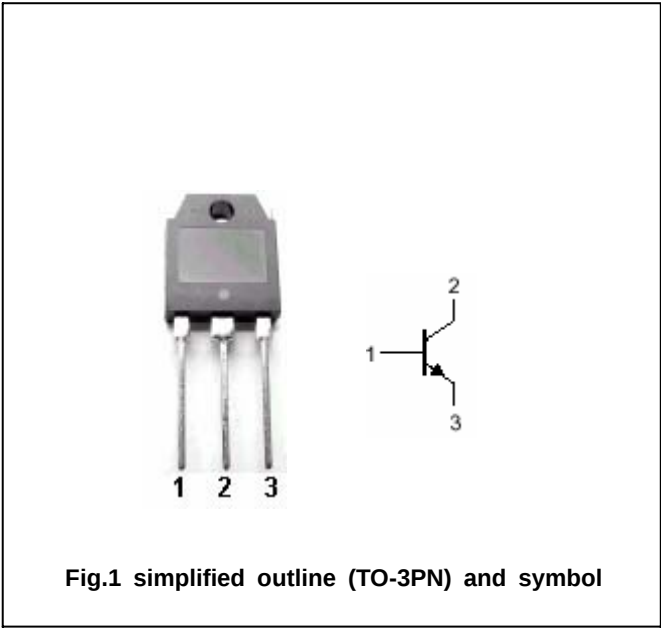


Fig.1 simplified outline (TO-3PN) and symbol

Absolute maximum ratings(Ta=)

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
V_{CBO}	Collector-base voltage	Open emitter	900	V
V_{CEO}	Collector-emitter voltage	Open base	550	V
V_{EBO}	Emitter-base voltage	Open collector	7	V
I_C	Collector current		5	A
I_{CM}	Collector current-peak		10	A
I_B	Base current		2.5	A
P_C	Collector power dissipation	$T_C=25$	80	W
T_j	Junction temperature		150	
T_{stg}	Storage temperature		-55~150	

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CHARACTERISTICS

Tj=25 unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{(BR)CEO}$	Collector-emitter breakdown voltage	$I_C=10mA$; $I_B=0$	550			V
V_{CEsat}	Collector-emitter saturation voltage	$I_C=1.8A$; $I_B=0.36A$			0.5	V
V_{BEsat}	Base-emitter saturation voltage	$I_C=1.8A$; $I_B=0.36A$			1.2	V
I_{CBO}	Collector cut-off current	$V_{CB}=800V$; $I_E=0$			100	μA
I_{EBO}	Emitter cut-off current	$V_{EB}=7V$; $I_C=0$			100	μA
h_{FE}	DC current gain	$I_C=1.8A$; $V_{CE}=4V$	10		25	
C_{OB}	Output capacitance	$I_E=0$; $V_{CB}=10V$; $f=1MHz$		50		pF
f_T	Transition frequency	$I_E=-0.35A$; $V_{CE}=12V$		6		MHz

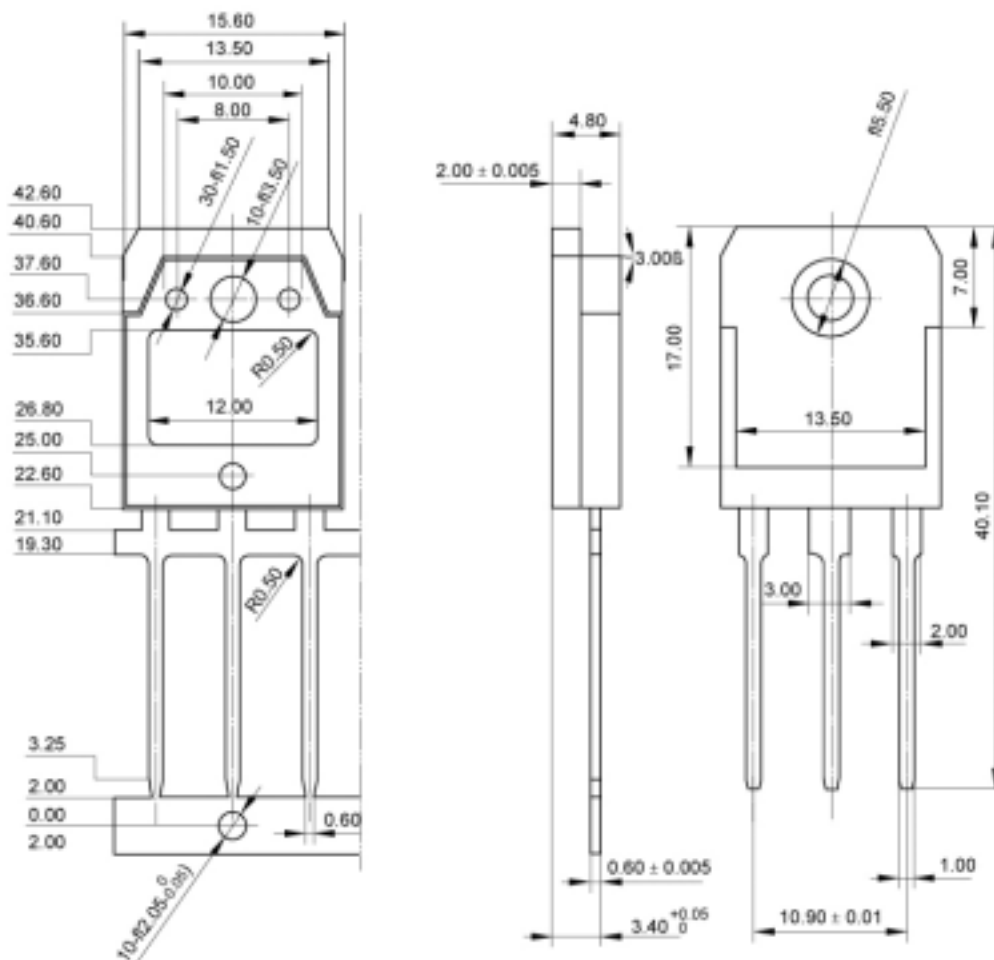
Switching times

t_{on}	Turn-on time	$I_C=1.8A$; $R_L=139\Omega$ $I_{B1}=0.27A$; $I_{B2}=-0.9A$ $V_{CC}=250V$			0.7	μs
t_s	Storage time				4.0	μs
t_f	Fall time				0.5	μs

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PACKAGE OUTLINE

Fig.2 outline dimensions (unindicated tolerance: $\pm 0.1\text{mm}$)

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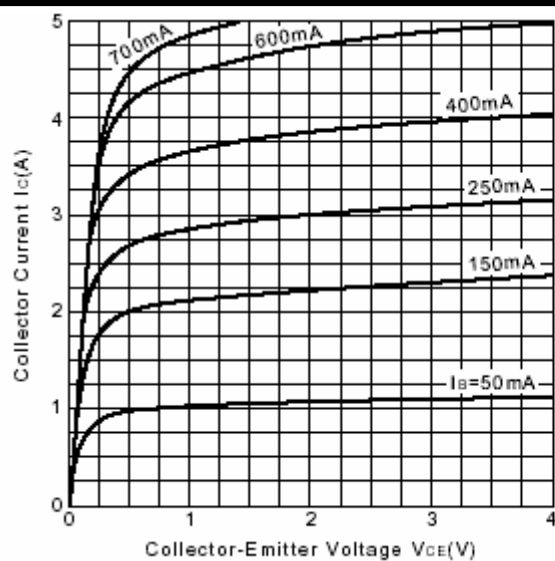


Fig.3 Static Characteristic

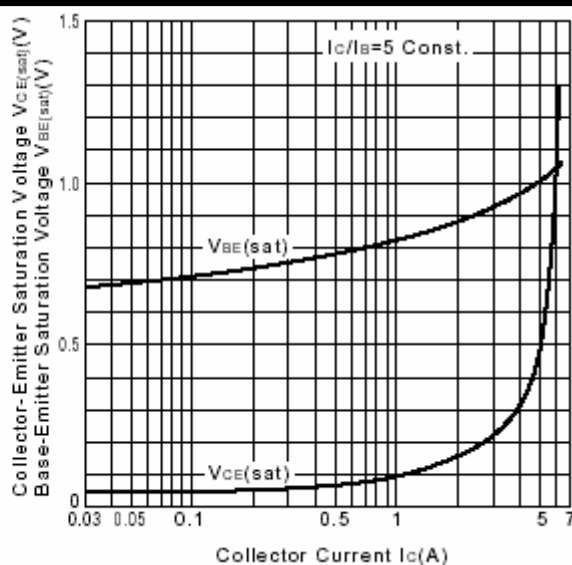
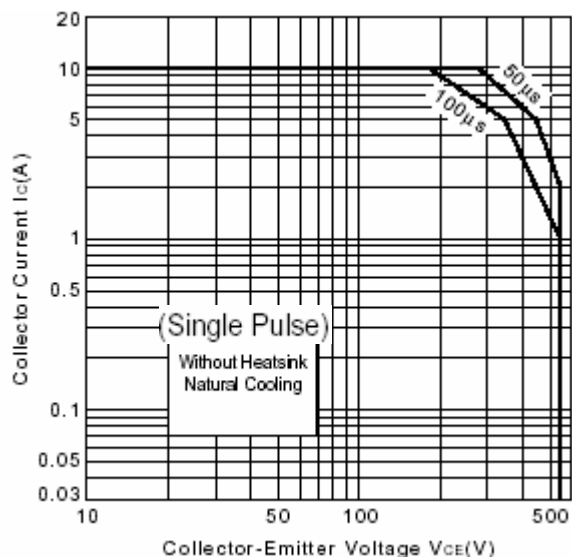
Fig.4 Base-Emmitter Saturation Voltage
Collector-Emmitter Saturation Voltage

Fig.5 Safe Operating Area

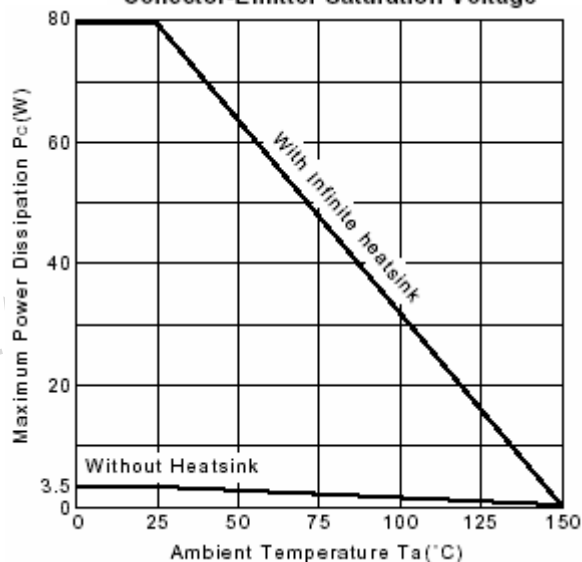


Fig.6 Power Derating

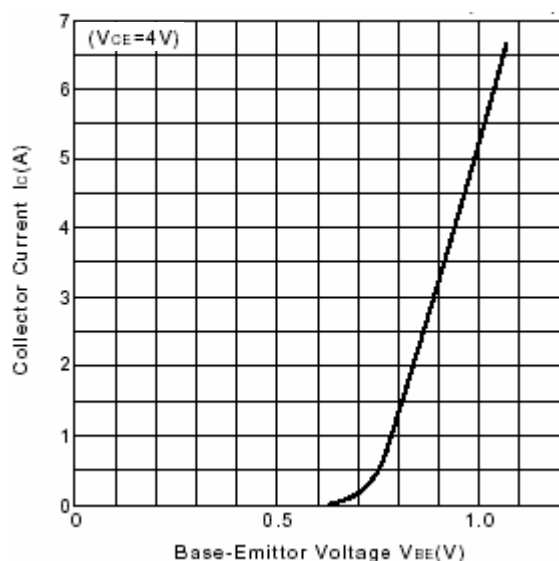
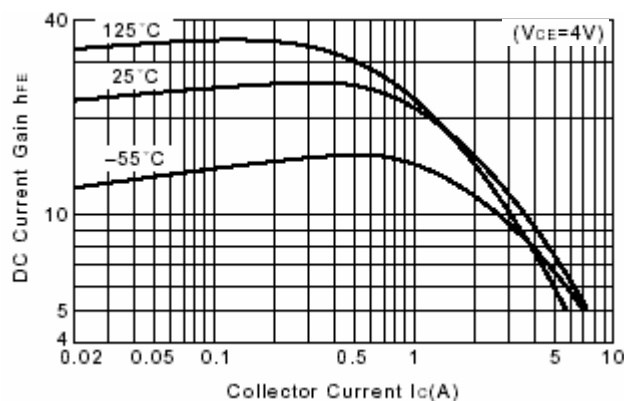
Fig.7 I_C - V_{BE} 

Fig.8 DC current Gain